

Stability of hexagonal solidification patterns

Mathis P lapp and Marcus Dejn ek

Laboratoire de Physique de la Matière Condensée,
CNRS/Ecole Polytechnique, 91128 Palaiseau, France

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We investigate the dynamics of cellular solidification patterns using three-dimensional phase-field simulations. The cells can organize into stable hexagonal patterns or exhibit unsteady evolutions. We identify the relevant secondary instabilities of regular hexagonal arrays and find that the stability boundaries depend significantly on the strength of crystalline anisotropy. We also find multiplet states that can be reached by applying well-defined perturbations to a pre-existing hexagonal array.

I. INTRODUCTION

Hexagonal patterns arise in many non-equilibrium systems when a two-dimensional translational symmetry is broken by a dynamic instability [1]. Well-known examples are Benard-Marangoni convection or Faraday surface waves. In directional solidification, where alloy samples are pulled with a fixed speed V in an externally imposed temperature gradient G , the planar solidification front becomes unstable above a critical value of the ratio $V=G$. Close above this threshold, the front develops shallow cells that often form regular hexagonal arrays [2, 3]; as $V=G$ increases, cells deepen and eventually form dendrites with lateral branches. Besides the interest of this sequence of morphological transitions as a model system for the physics of pattern formation [4], it also has practical importance because the morphology of the solidification front determines the spatial distribution of alloy components and defects in the solidified material that, in turn, influence its mechanical properties.

We focus here on two issues: the influence of crystalline anisotropy on pattern selection, and the existence of multiplet states consisting of several symmetry-broken cells. These questions have been examined in two dimensions (2D), both in thin-sample experiments [5, 6, 7] and numerically by boundary integral and phase-field methods [7, 8, 9]. The situation is less clear in three dimensions (3D), where the analysis of experimental data must account for the presence of convection in the bulk liquid, and numerical investigations have so far been restricted to rather short length and time scales [10, 11]. Here, we use an efficient formulation of the phase-field method [12] and a multi-scale simulation algorithm [13] to perform extensive quantitative 3D simulations of a symmetric model of directional solidification.

The influence of crystallographic effects on solidification patterns was already noticed in early experimental studies [2, 3]. It is by now well established that for freely growing dendrites, pattern selection is governed by small anisotropies of the solid-liquid surface tension and interface kinetics. More surprisingly, it was recently shown that anisotropy plays a crucial role even close above the instability threshold in directional solidification, where the cell shapes are round [6, 8]. For thin-sample experiments, where the system is quasi-two-dimensional, the anisotropy of the one-dimensional interface is controlled by the orientation of the crystal with respect to the sample plane [6]. Stable and regular steady states are obtained only for sufficiently strong anisotropy; for weak anisotropy, cells may split or disappear, and the solidification front never reaches steady state. In numerical simulations without anisotropy, cells are stable only in a narrow parameter range close to the onset of the primary instability; when anisotropy is included, stable solutions exist even far from threshold [8]. Here, we investigate in detail the stability of three-dimensional hexagonal cells and identify the relevant secondary instabilities. We find that the anisotropy has the same strong effect on array stability as in 2D.

Furthermore, we find triplet solutions; that is, groups of three cells that grow with their tips close together. This is the 3D equivalent of doublet fingers found in 2D both in experiments and simulations [5, 7, 9]. Similar 3D growth structures have been found in simulations of free growth in a channel [11], and as transients in experiments [14]. In our simulations, triplets can be generated in a controlled manner starting from a pre-existing hexagonal array.

II. MODEL AND IMPLEMENTATION

An alloy of overall composition c_0 is pulled with velocity V in a linear temperature field with its gradient G directed along the z axis. In the frame of the sample, the temperature is given by $T = T_0 + G(z - Vt)$, where solidification starts at $t = 0$ from a flat equilibrium interface of temperature T_0 at $z = 0$. This is the so-called frozen temperature approximation, valid for slow solidification and similar thermal conductivities of both phases. The phase field distinguishes between solid ($\phi = 1$) and liquid ($\phi = 0$). The concentration jump between solid and liquid c is assumed constant. Instead of the concentration field, which exhibits rapid variations across the interface, the

TABLE I: Simulation parameters. For all simulations, $W_0 = 1$, $D = 2$, the grid spacing is $\Delta x = 0.8$ and the time step $\Delta t = 0.05$. To obtain a "physical" capillary anisotropy γ_4 , a slightly higher value γ_4^0 has to be used in the model to correct for grid effects (see Ref. [12]).

γ_4	γ_4^0	γ_4^0	γ_4^0	γ_4^0
0.00	0.0029	3.482	1.018	-0.0180
0.01	0.0129	3.407	0.9965	0.00345
0.02	0.0231	3.330	0.975	0.0255
0.03	0.0334	3.262	0.955	0.0472

dimensionless field $u = (c - c_0) = c - 1$ is used. It is constant for an equilibrium interface and hence equivalent to a chemical potential. The time evolution of the fields is given by

$$\partial_t \phi = - \frac{F[\phi; u]}{\Gamma}; \quad (1)$$

$$\partial_t u = D \nabla^2 u + \partial_t \phi = 2; \quad (2)$$

where $\hat{n} = \mathbf{r} / |\mathbf{r}|$ is the unit normal to the interface, $\Gamma(\hat{n})$ is an orientation-dependent relaxation time, D is the solute diffusivity, and $F =$ denotes the functional derivative of the Lyapunov functional

$$F = \int_V \frac{W(\hat{n})^2}{2} (\nabla \cdot \mathbf{r})^2 + f(\phi) + g(\phi) u - \frac{z}{l_T} \nabla^2 u; \quad (3)$$

where $W(\hat{n})$ is the orientation-dependent interface thickness, $l_T = m \cos \theta$ is the thermal length with m being the liquidus slope in the phase diagram, and $f(\phi) = \frac{1}{2} \phi^2 + \frac{1}{4} \phi^4$ is a double-well potential. The quantity $u = (z - V t) / l_T$ is the local supersaturation, and its product with $g(\phi) = \frac{1}{2} \phi^2 + \frac{1}{4} \phi^4$ introduces a free energy difference between the two phases by tilting the double well, which provides the driving force for the phase transformation. Anisotropic surface tension with cubic symmetry and one principal axis aligned with the growth direction is implemented by $W(\hat{n}) = W_0 a(\hat{n})$ with $a(\hat{n}) = (1 - \gamma_4) [(1 + \gamma_4 (n_x^4 + n_y^4 + n_z^4)) / (1 - \gamma_4)]$. In the thin-interface limit [12], this model is equivalent to the classic free-boundary problem of solidification, in which u satisfies the diffusion equation in solid and liquid, the Stefan condition at the interface, $V_n = \hat{n} \cdot [\mathbf{D} \nabla u] - D \nabla u$, where V_n is the normal velocity of the interface, and the gradients of u are evaluated on the solid and liquid side of the interface, and the generalized Gibbs-Thomson condition at the interface,

$$u_{\text{int}} = \frac{z_{\text{int}}}{l_T} \nabla^2 u - \sum_{i=1}^3 \gamma_i a(\hat{n}) + \partial_t \phi_i a(\hat{n}) - \gamma_i \hat{n} \cdot \nabla u; \quad (4)$$

where γ_i are the local angles between \hat{n} and the two local principal directions on the interface, γ_i are the principal curvatures, $\gamma_0 = a_1 W_0$ is the capillary length, and $\Gamma(\hat{n}) = a_1 / (W_0 l_T) [1 - \gamma_4 (n_x^4 + n_y^4 + n_z^4)]$ is the kinetic coefficient, with $a_1 = 5/2 = 2.5$ and $a_2 = 0.6267$. Taking into account grid corrections as explained in detail in Ref. [12], the interface kinetics can be eliminated ($\Gamma = 0$) by setting $\Gamma(\hat{n}) = \gamma_0 (1 - \gamma_4) [(1 + \gamma_4 (n_x^4 + n_y^4 + n_z^4)) / (1 - \gamma_4)]$ and by choosing specific values for the constants γ_0 , γ_4 , and Δt that depend on D , the capillary anisotropy γ_4 and the discretization; the values used for our simulations are listed in table I.

The involved physical length scales are the thermal length l_T , the diffusion length $l_D = D / V$, and the capillary length d_0 . The stability of a planar interface is controlled by the parameter $\beta = l_T / l_D$. In experiments, β is usually varied by changing V at fixed G ; in the simulations, it is more efficient to vary G , and hence l_T at fixed $d_0 = l_D$. Typical experimental values for $d_0 = l_D$ are of the order 10^{-4} . However, due to computational constraints, such small values are too costly to simulate. Indeed, convergence of the phase-field method requires $W = l_D \beta > 1$ and $V = W / d_0 < 1$. The latter, combined with the requirement $\beta = 0$ (that is, $D = W^2 / l_T = d_0$), yields $W = l_D < d_0 = l_D$. Since the discretization is on the scale of W , whereas typical cell sizes are of order l_D or larger, the required number of grid points increases when $d_0 = l_D$ decreases. For the value $d_0 = l_D = 2.5 \times 10^{-2}$ used in most of our simulations, the morphological instability occurs at $\beta = 3.75$ (instead of $\beta = 2$ in the limit $d_0 = l_D \rightarrow 0$).

The above model has parallel liquidus and solidus lines and equal diffusivities in the solid and the liquid, whereas alloys exhibit strongly different diffusivities in the two phases and a temperature-dependent concentration jump. Nevertheless, this model has been shown to reproduce even complex qualitative features of pattern selection that are seen in 2D experiments [7], and computationally remains the most efficient model that captures the salient features of directional solidification, despite recent advances on more realistic alloy models [15].

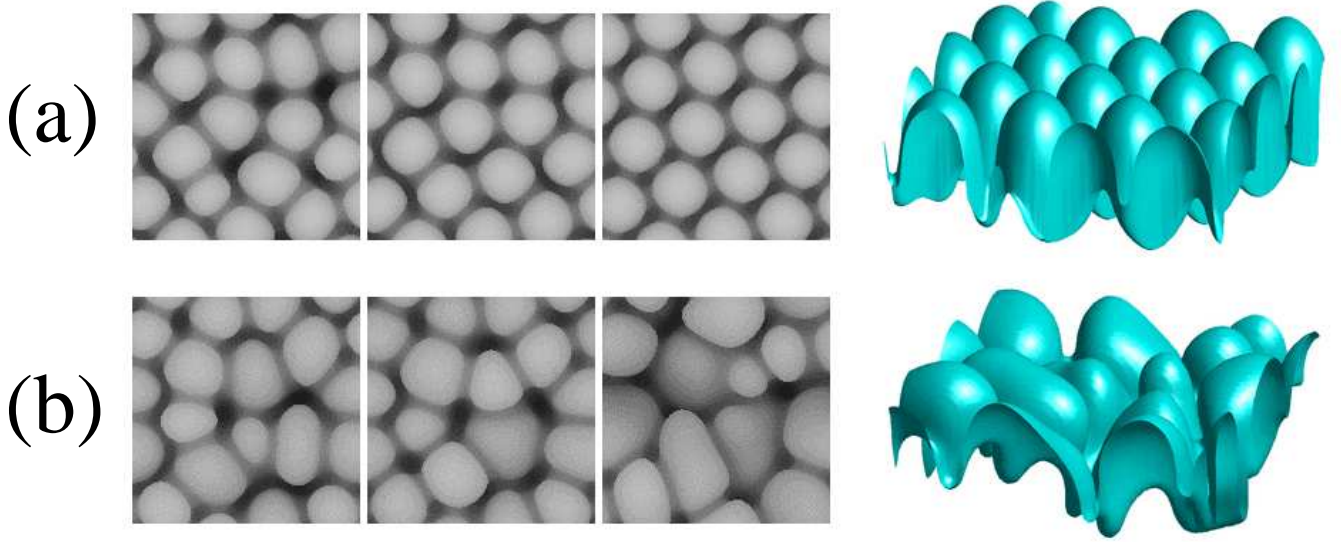


FIG. 1: Evolution of cellular patterns for $\epsilon = 12.5$ and (a) $\epsilon_4 = 0.03$ and (b) $\epsilon_4 = 0.02$. Left: top views of the growth front at $tD = t_0^2 = 320, 640$, and 19968 (the greyscale is proportional to the surface height; box size: $L_x = L_y = L_z = 128$); right: 3D view of the interface at the end of the run.

III. INFLUENCE OF ANISOTROPY

Simulations begin with an unstable planar steady-state interface, and numerical noise triggers the morphological instability. The subsequent evolution of the front dramatically depends on the anisotropy strength. For an anisotropy of $\epsilon_4 = 0.03$, some of the initial cells are eliminated, but most survive, become stable, and slowly drift over small distances until they form a perfectly regular lattice (Fig. 1a). In other runs, hexagonal arrays with defects are formed; in all cases, the interface shape converges to a stable steady-state solution. In contrast, for a slightly lower anisotropy ($\epsilon_4 = 0.02$) with otherwise identical conditions, the cells do not reach steady-state, and cell-elimination and cell-splitting events occur up to the end of our simulation runs (Fig. 1b).

As a first step toward the understanding of pattern selection, we investigate the stability of regular hexagonal arrays. We start from initial conditions as described in Fig. 2 and allow the cells to reach steady state at moderate values of ϵ . Then, we increase ϵ in small steps until a secondary instability threshold is reached. Two different instabilities are encountered. For large spacings, the cells oscillate and form a superlattice pattern shown in Fig. 2. Three equivalent sublattices of hexagonal symmetry emerge, with $\sqrt{3}$ times larger spacing than the basic pattern. All cells on each sublattice oscillate in phase with an exponential growth in amplitude over time. Eventually, the cells tip-split, and the subsequent dynamics is unsteady and similar to Fig. 1b. For smaller spacings, cell elimination occurs: all cells located on the same sublattice fall behind the others and are overgrown. The subsequent evolution is again unsteady. Finally, for ϵ very close to the onset of the primary instability, a few examples of isolated cell eliminations occurred that are probably the signature of an Eckhaus instability.

The geometry of the instability modes is entirely determined by the underlying hexagonal symmetry of the initial pattern [16]. Similar superlattice oscillations have been reported in simulations of two-dimensional amplitude equations [17, 18], and experimentally observed in fluid systems [19, 20]. The new feature here is the presence of anisotropy. Figure 3 shows the stability boundaries of oscillatory and cell elimination instabilities computed for several values of ϵ_4 . Whereas the cell elimination mode is only weakly sensitive to anisotropy, the critical cell spacing for the onset of the oscillatory mode is strongly anisotropy-dependent. Without anisotropy, the stability boundaries of the oscillatory and cell elimination modes cross and no stable states were found for $\epsilon > 9$. For $\epsilon_4 = 0.01$, a narrow range of stable states was found to extend to the largest values of ϵ investigated; this stable band becomes larger with increasing anisotropy. These findings correlate well with the overall behavior of the large-scale runs of Fig. 1, depicted in the inset of Fig. 3: Stable cellular arrays appear spontaneously only when a sufficiently large band of stable states is available.

Remarkably, the structure of the stability diagram is identical to the one obtained for 2D in Ref. [8]. The cell elimination and cell oscillation modes found here for hexagonal arrays are the equivalent of the well-known steady and oscillatory period-doubling instabilities found in 2D systems. To further investigate this similarity, we have performed two-dimensional simulations of our phase-field model and found that, for fixed simulation parameters, the stability

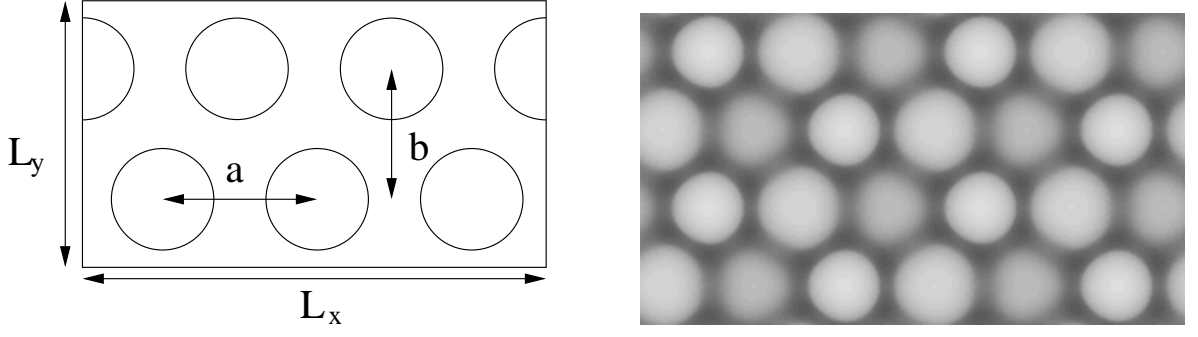


FIG. 2: Left: sketch of the simulated geometry: in a box of lateral size $L_x \times L_y$ with periodic boundary conditions, m rows of n cells may be generated by starting from a flat surface perturbed by the superposition of three plane waves; we define $a = L_x/n$ and $b = L_y/m$. Right: snapshot of an oscillatory instability that develops spontaneously in a box with 24 cells ($m = 4, n = 6$) for $\epsilon_4 = 5.4$, $a/l_D = 3.307$, $b/l_D = 2.880$, and $\epsilon_4 = 0.01$.

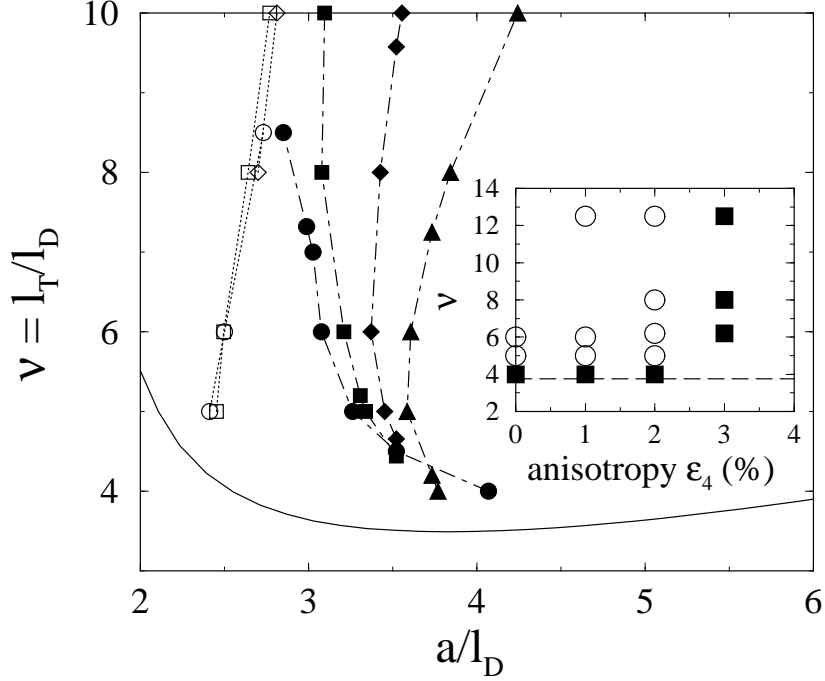


FIG. 3: Main plot: stability boundaries for hexagonal arrays for different anisotropies: 0% (circles), 1% (squares), 2% (diamonds), and 3% (triangles). Hexagonal arrays are stable between the limits of cell elimination (dotted lines and open symbols) and oscillations (dash-dotted lines and full symbols). The full line is the neutral stability line of the primary instability. Inset: behavior of large runs started from a flat surface. Filled squares: stable hexagons, open circles: unsteady evolution, dashed line: primary instability threshold.

diagrams in 2D and 3D are not identical; however, the critical spacings for the onset of instability differ by less than 20% in all cases investigated.

IV. OTHER INSTABILITY MODES

To investigate how the spatial structure of the oscillatory modes depends on the symmetry of the underlying steady-state solution, simulations starting from elongated hexagons were performed. By varying the aspect ratio of the simulation box, patterns ranging from rows of elongated hexagons ($b/a > 3/2$) over symmetric hexagons ($b/a = 3/2$) to squares ($b/a = 1/2$) can be generated. For a square lattice, there are only two equivalent sublattices, and a two-sublattice oscillation mode emerges. For rows of elongated hexagons, close to a one-dimensional symmetry,

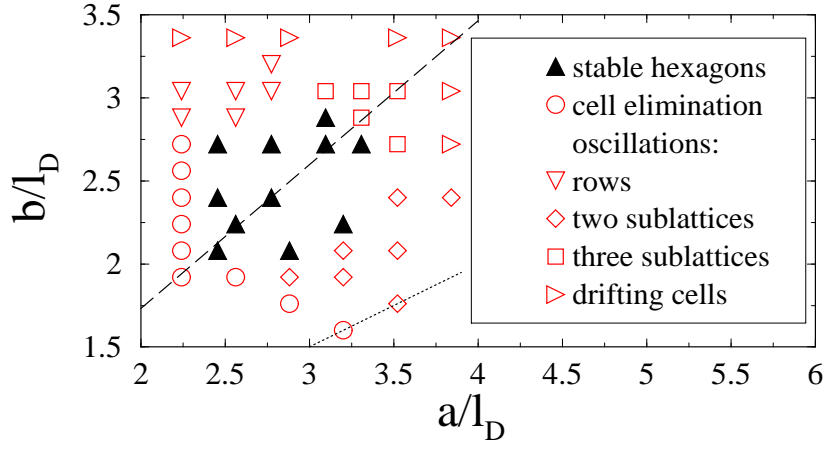


FIG. 4: Instabilities of deformed hexagons for $\gamma = 5$ and $\gamma_4 = 0$. The lengths a and b are defined in Fig. 2; the dashed line corresponds to regular hexagons, the dotted line to squares.

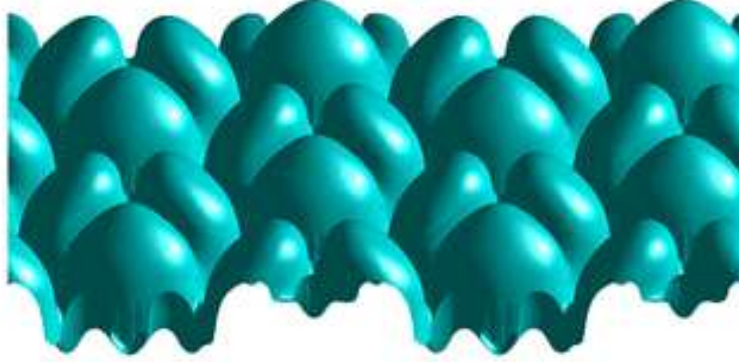


FIG. 5: Triplets at $\gamma = 12.5$, $a=l_D = 5.333$, $b=l_D = 4.640$, and $\gamma_4 = 0.02$. Six cells were simulated and the final picture was replicated four times to yield a clearer view.

in-phase oscillations of entire rows occur. For strongly elongated hexagons, a tilt instability is found that corresponds to a breaking of the parity symmetry: the cells become asymmetric and drift along their longer axis. However, these states are unstable with respect to subsequent oscillations. Figure 4 shows the symmetry of the fastest instability in the plane of the two lengths a and b defined in Fig. 2. We find a balloon of stable arrays consisting of regular or slightly elongated hexagons.

V. TRIPLETS

To search for multiplet states, we use a procedure inspired by the experimental method used in Ref. [7] to create doublets in thin-sample directional solidification. A UV-absorbing laser dye was used as solute, and by illuminating the sample with UV light through a mask, the temperature field was perturbed for a limited time with a well-defined spatial pattern. We implement a similar procedure by adding to the temperature field a perturbation $T(x; y)$ that has the symmetry of one of the three sublattices of Fig. 2, and whose minima are located over the "holes" between three cells. This promotes the growth of the surrounding cells, and their tips approach each other to form triplet fingers. Once the perturbation is switched off, the system relaxes to triplet states that remain stable for the duration of our simulations for large enough γ and large wavelengths (Fig. 5). For lower γ , the triplets exhibit instabilities similar to the usual cells, but no detailed investigation was carried out. Triplets never appeared spontaneously in our simulations: only unsteady evolutions resulted from random initial conditions, even for control parameters for which stable triplet states exist.

VI. CONCLUSION

We have studied the stability of hexagonal arrays and triplet fingers, and found that the crystalline anisotropy plays a crucial role in determining the stability bounds. Remarkably, despite the cubic symmetry of the anisotropy, the selected patterns are hexagonal, while square arrays are always unstable. Square cellular states have been calculated long ago using a numerical scheme valid only for shallow cells [21]. However, the geometry of the used simulation cell suppresses all large-scale oscillatory modes, such that no conclusion about their stability can be drawn. Nevertheless, the existence of other than hexagonal patterns cannot be ruled out in general, since it is known that the weakly nonlinear behavior of solidification fronts strongly depends on the alloy characteristics [4], and we have not carried out an exhaustive survey of the (large) parameter space.

The main approximations made in the present work are the constant concentration jump, the equal solute diffusivities, and the large value of $d_0 = l_D$. The two first can be easily levied by the use of a more general model [15]; the third remains a serious computational challenge. We expect most of our results to remain qualitatively valid for more realistic systems, since they depend only on the underlying symmetries and the stability of the cell tips. In that sense, it is interesting to note that unsteady evolutions similar to Fig. 1b and transient isolated multiplets have recently been observed in 3D experiments on transparent alloys [14].

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